

February 2013

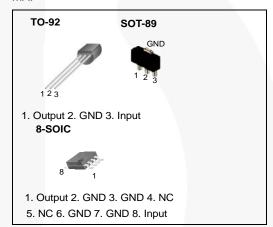
KA78LXXA / KA78L05AA 3-Terminal 0.1 A Positive Voltage Regulator

Features

- Maximum Output Current of 100 mA
- Output Voltage of 5 V, 6 V, 8 V, 9 V,10 V, 12 V, 15 V and 18 V
- Thermal Overload Protection
- · Short-Circuit Current Limiting
- Output Voltage Offered in ± 5% Tolerance

Description

The KA78LXXA / KA78L05AA series of fixed-voltage, monolithic, integrated circuit, voltage regulators are suitable for applications that require supply current up to 100 mA.



Ordering Information

Product Number	Package	Packing Method	Output Voltage Tolerance	Operating Temperature
KA78L05AZTA		Ammo	/	
KA78L05AZBU		Bulk		
KA78L06AZTA		Ammo		
KA78L08AZTA	•	Ammo		
KA78L09AZTA	TO-92	Ammo		
KA78L10AZTA	•	Ammo		
KA78L12AZTA		Ammo	± 5%	0 ~ +125 °C
KA78L15AZTA		Ammo		0~+125 C
KA78L18AZTA		Ammo		
KA78L05AMTF		Tape & Reel		
KA78L08AMTF	SOT-89	Tape & Reel		
KA78L12AMTF	,	Tape & Reel		
KA78L05ADTF	8-SOIC	Tape & Reel		
KA78L05AAZTA	TO-92	Ammo	± 3%	

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Block Diagram

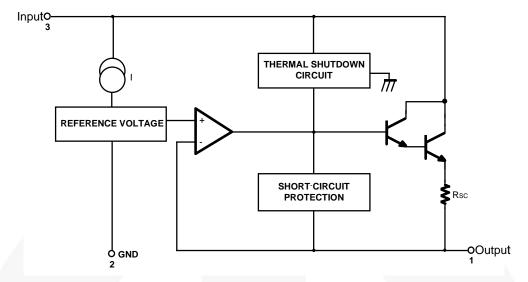


Figure 1. Block Diagram

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $T_A = 25^{\circ}\text{C}$ unless otherwise noted.

Symbol	Parai	meter	Value	Unit
W	Input Voltage	$V_O = 5 \text{ V to } 8 \text{ V}$		V
V _I	Input Voltage	V _O = 12 V to 18 V	35	V
T_J	Operating Junction Temperature Ra	nge	0 to +150	°C
T _{STG}	Storage Temperature Range		-65 to +150	°C
$R_{\theta JC}$	Thermal Resistance, Junction-Case	TO-92	50	°C/W
		TO-92	150	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction-Air	SOT-89	225	°C/W
		8-SOIC	160	°C/W

Electrical Characteristics (KA78L05A)

 $V_I = 10 \text{ V, } I_O = 40 \text{ mA, } 0^{\circ}C \leq T_J \leq 125^{\circ}C, \ C_I = 0.33 \ \mu\text{F, } C_O = 0.1 \ \mu\text{F, unless otherwise specified.}$

Symbol	Paramete	er	Cond	ditions	Min.	Тур.	Max.	Unit
Vo	Output Voltage		T _J = 25°C		4.8	5.0	5.2	V
41/	Line Regulation ⁽¹⁾		T _{.J} = 25°C	7 V ≤ V _I ≤ 20 V		8	150	mV
ΔV_{O}	Line Regulation V		1j = 25 C	8 V ≤ V _I ≤ 20 V		6	100	mV
ΔV_{Ω}	Load Regulation ⁽¹⁾		T - 25°C	$1 \text{ mA} \le I_O \le 100 \text{ mA}$		11	60	mV
ΔvO	Load Regulation V		$T_J = 25^{\circ}C$	1 mA \leq I _O \leq 40 mA		5.0	30	mV
V	Output Valtage		7 V ≤ V _I ≤ 20 V	1 mA \leq I _O \leq 40 mA			5.25	V
Vo	Output Voltage		$7 \text{ V} \leq \text{V}_{\text{I}} \leq \text{V}_{\text{MAX}}^{(2)}$	1 mA \leq I _O \leq 70 mA	4.75		5.25	V
IQ	Quiescent Current		T _J = 25°C			2.0	5.5	mA
ΔI_{Q}	Quiescent Current	With Line	8 V ≤V _I ≤ 20 V				1.5	mA
ΔI_Q	Change	With Load	$1 \text{ mA} \le I_{O} \le 40 \text{ mA}$	4			0.1	mA
V _N	Output Noise Voltag	е	$T_A = 25^{\circ}C$, 10 Hz	≤ f ≤ 100 kHz		40		μV/Vo
$\Delta V_{O}/\Delta T$	Temperature Coefficient of V _O		$I_O = 5 \text{ mA}$			-0.65		mV/°C
RR	Ripple Rejection		f = 120 Hz, 8 V ≤ '	$V_1 \le 18 \text{ V}, T_J = 25^{\circ}\text{C}$	41	80		dB
V_D	Dropout Voltage		T _J = 25°C			1.7		V

- 1. The maximum steady-state usable output current and input voltage are very dependent on the heat sinking and/or lead length of the package. The data above represents pulse test conditions with junction temperature as indicated at the initiation of tests.
- 2. Power dissipation: $P_D \le 0.75 \text{ W}$.

Electrical Characteristics (KA78L06A)

 $V_I = 12 \text{ V, } I_O = 40 \text{ mA, } 0^{\circ}\text{C} \leq T_J \leq 125^{\circ}\text{C, } C_I = 0.33 \text{ } \mu\text{F, } C_O = 0.1 \text{ } \mu\text{F, unless otherwise specified.}$

Symbol	Paramete	er	С	onditions	Min.	Тур.	Max.	Unit
Vo	Output Voltage		T _J = 25°C	T _J = 25°C		6.00	6.25	V
4)/	Line Regulation (3)		T = 25°C	8.5 V ≤ V _I ≤ 20 V		64	175	mV
ΔV_{O}	Line Regulation V		$T_J = 25^{\circ}C$	9 V ≤ V _I ≤ 20 V		54	125	mV
۸\/	Load Regulation (3)		T _{.J} = 25°C	$1 \text{ mA} \le I_{O} \le 100 \text{ mA}$		12.8	80.0	mV
ΔV_{O}	Load Regulation (*)		1 _J = 25 C	$1 \text{ mA} \le I_{O} \le 70 \text{ mA}$		5.8	40.0	mV
\/	Output Voltage		$8.5 \text{ V} \le \text{V}_{\text{I}} \le 20 \text{ V}, 1 \text{ mA} \le \text{I}_{\text{O}} \le 40 \text{ mA}$				6.3	V
Vo	Output voltage	Output Voltage		$8.5 \text{ V} \le \text{V}_{\text{I}} \le \text{V}_{\text{MAX}}^{(4)}, 1 \text{ mA} \le \text{I}_{\text{O}} \le 70 \text{ mA}$			6.3	V
1	Quiescent Current		T _J = 25°C				5.5	mA
ΙQ	Quiescent Current		T _J = 125°C			3.9	6.0	mA
ΔI_Q	Quiescent Current	With Line	9 V ≤ V _I ≤ 20 V	/			1.5	mA
ΔI_{Q}	Change	With Load	$1 \text{ mA} \le I_O \le 40$) mA			0.1	mA
V _N	Output Noise Voltag	е	$T_A = 25^{\circ}C, 10$	Hz ≤ f ≤ 100 kHz		40		μV/Vo
$\Delta V_O/\Delta T$	Temperature Coefficient of V _O		I _O = 5 mA			0.75		mV/°C
RR	Ripple Rejection		f = 120 Hz, 10	$V \le V_I \le 20 \text{ V}, T_J = 25^{\circ}\text{C}$	40	46		dB
V_D	Dropout Voltage		$T_J = 25^{\circ}C$			1.7		V

- 3. The maximum steady-state usable output current and input voltage are very dependent on the heat sinking and/or lead length of the package. The data above represents pulse test conditions with junction temperature as indicated at the initiation of tests.
 4. Power dissipation: P_D ≤ 0.75 W.

Electrical Characteristics (KA78L08A)

 $V_I = 14 \text{ V, } I_O = 40 \text{ mA, } 0^{\circ}\text{C} \leq T_J \leq 125^{\circ}\text{C, } C_I = 0.33 \text{ } \mu\text{F, } C_O = 0.1 \text{ } \mu\text{F, unless otherwise specified.}$

Symbol	Parameter		Condi	tions	Min.	Тур.	Max.	Unit
Vo	Output Voltage		$T_J = 25^{\circ}C$		7.7	8.0	8.3	V
41/	Line Regulation (5	5)	T _J = 25°C	10.5 V ≤ V _I ≤ 23 V		10	175	mV
ΔV_{O}	Line Regulation \	<i>,</i>	1j = 25 C	11 V ≤ V _I ≤ 23 V		8	125	mV
41/	Load Regulation (5)	T _{.1} = 25°C	$1 \text{ mA} \le I_O \le 100 \text{ mA}$		15	80	mV
ΔV_{O}	Load Regulation	/	1 _J = 25 C	1 mA \leq I _O \leq 40 mA		8	40	mV
\/	Output Voltage		$10.5 \text{ V} \le \text{V}_{\text{I}} \le 23 \text{ V}$	1 mA \leq I _O \leq 40 mA	7.6		8.4	V
Vo	Output Voltage		$10.5 \text{ V} \le \text{V}_{\text{I}} \le \text{V}_{\text{MAX}}^{(6)}$	$1 \text{ mA} \le I_O \le 70 \text{ mA}$	7.6		8.4	V
IQ	Quiescent Curren	t	$T_J = 25^{\circ}C$			2.0	5.5	mA
ΔI_{Q}	Quiescent	With Line	11 V ≤ V _I ≤ 23 V				1.5	mA
ΔI_{Q}	Current Change	With Load	$1 \text{ mA} \le I_O \le 40 \text{ mA}$				0.1	mA
V _N	Output Noise Volt	age	$T_A = 25^{\circ}C$, 10 Hz \leq f \leq	≤100 kHz		60		μV/Vo
ΔV _O /ΔΤ	Temperature Coefficient of V _O		I _O = 5 mA			-0.8		mV/°C
RR	Ripple Rejection		f = 120 Hz, 11 V ≤ V _I :	≤ 21 V, T _J = 25°C	39	70		dB
V_D	Dropout Voltage		$T_J = 25^{\circ}C$		1	1.7		V
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- 5. The maximum steady-state usable output current and input voltage are very dependent on the heat sinking and/or lead length of the package. The data above represents pulse test conditions with junction temperature as indicated at the initiation of tests.

 6. Power dissipation: $P_D \le 0.75 \text{ W}$.

Electrical Characteristics (KA78L09A)

 $V_I = 15 \text{ V, } I_O = 40 \text{ mA, } 0^{\circ}\text{C} \leq T_J \leq 125^{\circ}\text{C, } C_I = 0.33 \text{ } \mu\text{F, } C_O = 0.1 \text{ } \mu\text{F, unless otherwise specified.}$

Symbol	Paramet	er	Condi	tions	Min.	Тур.	Max.	Unit
Vo	Output Voltage		$T_J = 25^{\circ}C$		8.64	9.00	9.36	V
4)/	Line Regulation (7)		T _{.l} = 25°C	11.5 V ≤ V _I ≤ 24 V		90	200	mV
ΔV_{O}	Line Regulation V		1j = 25 C	13 V ≤ V _I ≤ 24 V		100	150	mV
4)/	Load Regulation (7))	T _ 25°C	$1 \text{ mA} \le I_{O} \le 100 \text{ mA}$		20	90	mV
ΔV_{O}	Load Regulation V		$T_J = 25^{\circ}C$	$1 \text{ mA} \le I_O \le 40 \text{ mA}$		10	45	mV
V	Outrut Valtage		$11.5 \text{ V} \le \text{V}_{\text{I}} \le 24 \text{ V}$	$1 \text{ mA} \le I_{O} \le 40 \text{ mA}$	8.55		9.45	V
V _O	Output Voltage		11.5 $V \le V_I \le V_{MAX}^{(8)}$	$1 \text{ mA} \le I_O \le 70 \text{ mA}$	8.55		9.45	V
ΙQ	Quiescent Current		T _J = 25°C			2.1	6.0	mA
ΔI_Q	Quiescent Current	With Line	13 V ≤ V _I ≤ 24 V				1.5	mA
ΔI_{Q}	Change	With Load	1 mA \leq I _O \leq 40 mA				0.1	mA
V _N	Output Noise Voltage		$T_A = 25^{\circ}C, 10 \text{ Hz} \le f \le$	≤ 100 kHz		70		μV/Vo
$\Delta V_O/\Delta T$	Temperature Coefficient of V _O		I _O = 5 mA			-0.9		mV/°C
RR	Ripple Rejection		f = 120 Hz, 12 V ≤ V _I :	≤ 22 V, T _J = 25°C	38	44		dB
V_{D}	Dropout Voltage		$T_J = 25^{\circ}C$			1.7	70.	V

- 7. The maximum steady-state usable output current and input voltage are very dependent on the heat sinking and/or lead length of the package. The data above represents pulse test conditions with junction temperature as indicated at the initiation of tests. 8. Power dissipation: $P_D \le 0.75 \text{ W}$.

Electrical Characteristics (KA78L10A)

 $V_I = 16 \text{ V, } I_O = 40 \text{ mA, } 0 \text{ } ^{\circ}\text{C} \leq T_J \leq 125 \text{ } ^{\circ}\text{C, } C_I = 0.33 \text{ } \mu\text{F, } C_O = 0.1 \text{ } \mu\text{F, unless otherwise specified.}$

Symbol	Paramete	er	(Conditions	Min.	Тур.	Max.	Unit
Vo	Output Voltage		$T_J = 25^{\circ}C$		9.6	10.0	10.4	V
41/	Line Regulation ⁽⁹⁾		T _ 25°C	12.5 V ≤ V _I ≤ 25 V		100	220	mV
ΔV_{O}	Line Regulation		$T_J = 25^{\circ}C$	14 V ≤ V _I ≤ 25 V		100	170	mV
41/	Load Regulation ⁽⁹⁾		T _J = 25°C	1 mA ≤ I _O ≤ 100 mA		20	94	mV
ΔV_{O}	Load Regulation 7		1 J = 25 C	1 mA ≤ I _O ≤ 70 mA		10	47	mV
			$12.5 \text{ V} \leq \text{V}_{\text{I}} \leq$	25 V, 1 mA ≤ I _O ≤ 40 mA	9.5		10.5	
Vo	Output Voltage		12.5 $V \le V_1 \le 1$ 1 mA $\le I_0 \le 1$		9.5		10.5	V
	Ouissant Current		T _J = 25°C				6.0	A
IQ	Quiescent Current		T _J =125°C			4.2	6.5	mA
ΔI_{Q}	Quiescent Current	With Line	12.5 V ≤ V _I ≤	25 V			1.5	mA
ΔI_{Q}	Change	With Load	1 mA \leq $I_O \leq$	40 mA			0.1	mA
V _N	Output Noise Voltage	е	$T_A = 25^{\circ}C$, 10 Hz $\leq f \leq$ 100 kHz			74		μV/Vo
$\Delta V_{O}/\Delta T$	Temperature Coeffic	ient of V _O	$I_O = 5 \text{ mA}$			0.95		mV/°C
RR	Ripple Rejection		$f = 120 \text{ Hz}, 15 \text{ V} \le \text{V}_{\text{I}} \le 25 \text{ V}, \text{T}_{\text{J}} = 25^{\circ}\text{C}$		38	43		dB
V_{D}	Dropout Voltage		T _J = 25°C			1.7		V

- 9. The maximum steady-state usable output current and input voltage are very dependent on the heat sinking and/or lead length of the package. The data above represents pulse test conditions with junction temperature as indicated at the initiation of tests.
- 10. Power dissipation: $P_D \le 0.75 \text{ W}$.

Electrical Characteristics (KA78L12A)

 $V_I = 19 \text{ V, } I_O = 40 \text{ mA, } 0^{\circ}\text{C} \leq T_J \leq 125^{\circ}\text{C, } C_I = 0.33 \text{ } \mu\text{F, } C_O = 0.1 \text{ } \mu\text{F, unless otherwise specified.}$

Symbol	Parame	ter	Condit	tions	Min.	Тур.	Max.	Unit
Vo	Output Voltage		T _J = 25°C		11.5	12.0	12.5	V
$\Delta V_{\mathbf{O}}$	Line Regulation (1	1)	T _{.1} = 25°C	14.5 V ≤ V _I ≤ 27 V		20	250	mV
ΔνΟ	Line Regulation	,	1j = 25 C	16 V ≤ V _I ≤ 27 V		15	200	mV
41/	Load Regulation (11)	$T_J = 25^{\circ}C$	$1 \text{ mA} \le I_{O} \le 100 \text{ mA}$		20	100	mV
ΔV _O	Load Regulation	,		$1 \text{ mA} \le I_{O} \le 40 \text{ mA}$		10	50	mV
V	Output Voltage		$14.5 \text{ V} \le \text{V}_{\text{I}} \le 27 \text{ V}$	$1 \text{ mA} \le I_{O} \le 40 \text{ mA}$	11.4		12.6	V
Vo	Output voltage		$14.5 \text{ V} \le \text{V}_{\text{I}} \le \text{V}_{\text{MAX}}^{(12)}$	$1 \text{ mA} \le I_{O} \le 70 \text{ mA}$	11.4		12.6	V
IQ	Quiescent Current	t	T _J = 25°C			2.1	6.0	mA
ΔI_{Q}	Quiescent	With Line	16 V ≤ V _I ≤ 27 V				1.5	mA
ΔI_{Q}	Current Change	With Load	$1 \text{ mA} \le I_{O} \le 40 \text{ mA}$				0.1	mA
V _N	Output Noise Voltage		$T_A = 25^{\circ}C, 10 \text{ Hz} \le f \le$	100 kHz		80		μV/Vo
$\Delta V_{O}/\Delta T$	Temperature Coefficient of V _O		I _O = 5 mA			-1.0		mV/°C
RR	Ripple Rejection		f = 120 Hz, 15 V ≤ V _I ≤	25 V, T _J = 25°C	37	65		dB
V_D	Dropout Voltage		T _J = 25°C			1.7		V

- 11. The maximum steady-state usable output current and input voltage are very dependent on the heat sinking and/or lead length of the package. The data above represents pulse test conditions with junction temperature as indicated at the initiation of tests. 12. Power dissipation: $P_D \le 0.75 \text{ W}$.

Electrical Characteristics (KA78L15A)

 $V_{I} = 23 \text{ V, } I_{O} = 40 \text{ mA, } 0^{\circ}\text{C} \leq T_{J} \leq 125^{\circ}\text{C, } C_{I} = 0.33 \text{ } \mu\text{F, } C_{O} = 0.1 \text{ } \mu\text{F, unless otherwise specified.}$

Symbol	Parame	eter	Condit	ions	Min.	Тур.	Max.	Unit
Vo	Output Voltage		T _J = 25°C		14.4	15.0	15.6	V
41/	Line Regulation ⁽¹	13)	T = 25°C	17.5 V ≤ V _I ≤ 30 V		25	300	mV
ΔV_{O}	Line Regulation	-,	$T_J = 25^{\circ}C$	20 V ≤ V _I ≤ 30 V		20	250	mV
41/	Load Regulation	(13)	T - 25°C	$1 \text{ mA} \le I_{O} \le 100 \text{ mA}$		25	150	mV
ΔV_{O}	Load Regulation	/	$T_J = 25^{\circ}C$	1 mA \leq I _O \leq 40 mA		12	75	mV
\/	Output Valtage		$17.5 \text{ V} \le \text{V}_1 \le 30 \text{ V}$	$1 \text{ mA} \le I_O \le 40 \text{ mA}$	14.25		15.75	V
Vo	Output Voltage		$17.5 \text{ V} \le \text{V}_{\text{I}} \le \text{V}_{\text{MAX}}^{(14)}$	$1 \text{ mA} \le I_O \le 70 \text{ mA}$	14.25		15.75	V
ΙQ	Quiescent Curre	nt	T _J = 25°C			2.1	6.0	mA
ΔI_Q	Quiescent	With Line	20 V ≤ V _I ≤ 30 V				1.5	mA
ΔI_Q	Current Change	With Load	1 mA ≤ I _O ≤ 40 mA				0.1	mA
V _N	Output Noise Vo	ltage	$T_A = 25^{\circ}C, 10 \text{ Hz} \le f \le$	100 kHz		90		μV/Vo
ΔV _O /ΔΤ	Temperature Coefficient of V _O		I _O = 5 mA			-1.3		mV/°C
RR	Ripple Rejection		f = 120 Hz, 18.5 V ≤ V	_I ≤ 28.5 V, T _J =25°C	34	60		dB
V_D	Dropout Voltage		T _J = 25°C		\;	1.7		V
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^{13.} The maximum steady-state usable output current and input voltage are very dependent on the heat sinking and/or lead length of the package. The data above represents pulse test conditions with junction temperature as indicated at the initiation of tests. 14. Power dissipation: $P_D \le 0.75 \text{ W}$.

Electrical Characteristics (KA78L18A)

 $V_I = 27 \text{V, I}_O = 40 \text{mA, } 0^\circ \text{C} \leq \text{T}_J \leq 125^\circ \text{C, C}_I = 0.33 \ \mu\text{F, C}_O = 0.1 \ \mu\text{F, unless otherwise specified.}$

Symbol	Parame	eter	Condi	tions	Min.	Тур.	Max.	Unit
Vo	Output Voltage		T _J = 25°C		17.3	18.0	18.7	V
41/	Line Regulation (1	5)	T _{.1} = 25°C	21 V ≤ V _I ≤ 33 V		145	300	mV
ΔV_{O}	Line Regulation	,	1j = 25 C	22 V ≤ V _I ≤ 33 V		135	250	mV
ΔV _O	Load Regulation (15)	T = 25°C	1 mA ≤ I _O ≤100 mA		30	170	mV
ΔνΟ	Load Regulation	,	$T_J = 25^{\circ}C$	$1 \text{ mA} \le I_{O} \le 40 \text{ mA}$		15	85	mV
W	Output Voltage		21 V ≤ V _I ≤ 33 V	$1 \text{ mA} \le I_{O} \le 40 \text{ mA}$	17.1		18.9	V
Vo	Output voltage		$21V \le V_I \le V_{MAX}^{(16)}$	$1 \text{ mA} \le I_{O} \le 70 \text{ mA}$	17.1		18.9	V
ΙQ	Quiescent Curren	t	T _J = 25°C			2.2	6.0	mA
ΔI_Q	Quiescent	With Line	21 V ≤ V _I ≤ 33 V				1.5	mA
ΔI_Q	Current Change	With Load	1 mA ≤ I _O ≤ 40 mA				0.1	mA
V _N	Output Noise Volt	age	$T_A = 25^{\circ}C, 10 \text{ Hz} \le f$	≤ 100 kHz		150		μV/Vo
$\Delta V_{O}/\Delta T$	Temperature Coefficient of V _O		I _O = 5 mA			-1.8		mV/°C
RR	Ripple Rejection		f = 120 Hz, 23 V ≤ V	_I ≤ 33V, T _J = 25°C	34	48		dB
V_D	Dropout Voltage		T _J = 25°C			1.7		V

^{15.} The maximum steady-state usable output current and input voltage are very dependent on the heat sinking and/or lead length of the package. The data above represents pulse test conditions with junction temperature as indicated at the initiation of tests. 16. Power dissipation: $P_D \le 0.75 \text{ W}$.

Electrical Characteristics (KA78L05AA)

 V_I = 10 V, I_O = 40 mA, 0°C \leq T $_J$ \leq 125°C, C_I = 0.33 μ F, C_O = 0.1 μ F, unless otherwise specified.

Paramet	er	Cond	Min.	Тур.	Max.	Unit	
Output Voltage		T _J = 25°C		4.9	5.0	5.1	V
Line Pegulation (17)		T 25°C	7 V ≤ V _I ≤ 20 V		8	150	mV
Line Regulation V		1 1 = 25 0	8 V ≤ V _I ≤ 20 V		6	100	mV
Load Pagulation (17	")	T 25°C	$1 \text{ mA} \le I_{O} \le 100 \text{ mA}$		11	50	mV
Load Regulation	,	T _J = 25°C	1 mA \leq I _O \leq 40 mA		5.0	25	mV
Outrut Valtage		$7 \text{ V} \leq \text{V}_1 \leq 20 \text{ V}$	1 mA \leq I _O \leq 40 mA			5.15	V
Output Voltage		$7 \text{ V} \leq \text{V}_{\text{I}} \leq \text{V}_{\text{MAX}}^{(18)}$	1 mA ≤ I _O ≤ 70 mA	4.85		5.15	V
Quiescent Current		$T_J = 25^{\circ}C$			2.0	5.5	mA
Quiescent Current	With Line	8 V ≤V _I ≤ 20 V				1.5	mA
Change	With Load	1 mA \leq I _O \leq 40 mA				0.1	mA
Output Noise Voltage		$T_A = 25^{\circ}C$, 10 Hz \leq	≦ f ≤ 100 kHz		40		μV/Vo
Temperature Coefficient of V _O		I _O = 5 mA			-0.65		mV/°C
Ripple Rejection		f = 120 Hz, 8 V ≤ V	' _I ≤ 18 V, T _J = 25°C	41	80		dB
Dropout Voltage		T _J = 25°C			1.7		V
	Output Voltage Line Regulation (17) Load Regulation (17) Output Voltage Quiescent Current Quiescent Current Change Output Noise Voltage Temperature Coeffi	Line Regulation (17) Load Regulation (17) Output Voltage Quiescent Current Quiescent Current Change With Line With Load Output Noise Voltage Temperature Coefficient of V _O Ripple Rejection	$\begin{array}{llllllllllllllllllllllllllllllllllll$	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$

- 17. The maximum steady-state usable output current and input voltage are very dependent on the heat sinking and/or lead length of the package. The data above represents pulse test conditions with junction temperature as indicated at the initiation of tests.

 18. Power dissipation: $P_D \le 0.75 \text{ W}$.

Typical Application

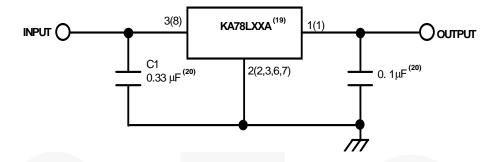


Figure 2. Typical Application

- 19. To specify an output voltage, substitute voltage value for "XX".
- 20. Bypass capacitors are recommend for optimum stability and transient response and should be located as close as possible to the regulator.

Physical Dimensions

SOT-89

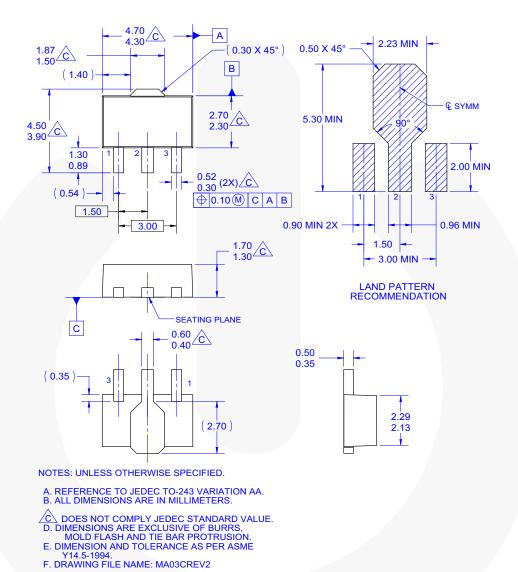


Figure 3. 3-Lead, SOT-89, JEDEC TO-243, Option AA

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Physical Dimensions (Continued)

TO-92 Straight Lead for Bulk Packing

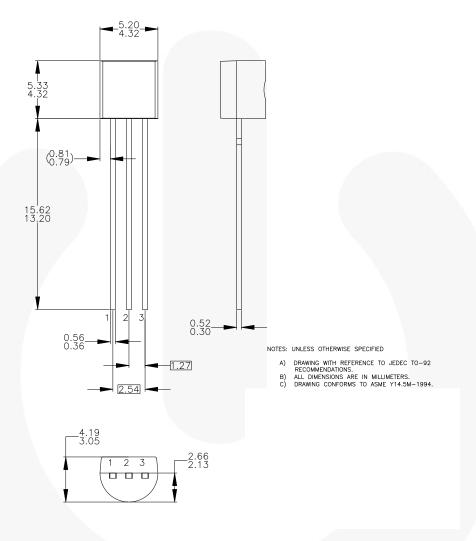


Figure 4. 3LD, TO-92, MOLDED STD STRAIGHT LD(NO EOL CODE)

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Physical Dimensions (Continued)

TO-92 Formed Lead For T&R and Ammo Packing

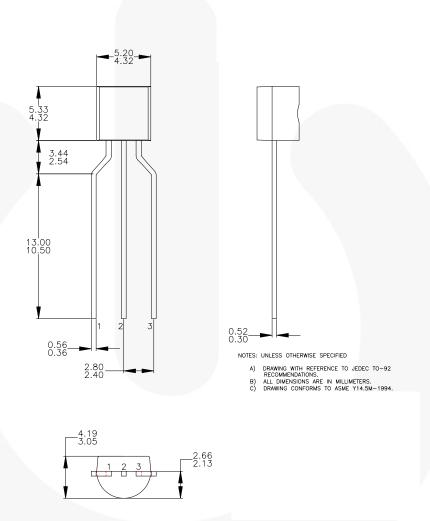


Figure 5. 3LD, TO-92, MOLDED 0.200 IN LINE SPACING LD FORM (J61Z OPTION)

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Physical Dimensions (Continued)

8-SOIC

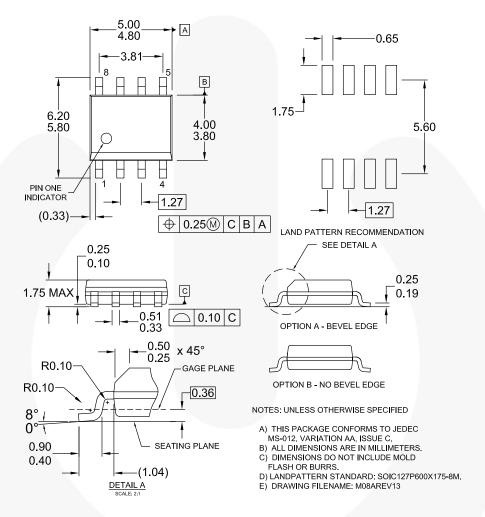


Figure 6. 8LD, SOIC, JEDEC MS-012, 0.150" NARROW BODY

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